NSN 5961-01-331-8729

A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-331-8729 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.180 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.056 inches and 0.075 inches **Function For Which Designed:** Switching **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 100.0 reverse breakdown voltage, dc all semiconductor device diode and 75.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute all semiconductor device diode and 500.00 milliamperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: